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September 2014

FDMA86151L

Single N-Channel PowerTrench® MOSFET

100 V, 3.3 A, 88 mΩ

Features

- Max $r_{DS(on)}$ = 88 m Ω at V_{GS} = 10 V, I_D = 3.3 A
- Max $r_{DS(on)}$ = 132 m Ω at V_{GS} = 4.5 V, I_D = 2.7 A
- Low Profile 0.8 mm maximum in the new package MicroFET 2x2 mm
- Free from halogenated compounds and antimony oxides
- RoHS Compliant

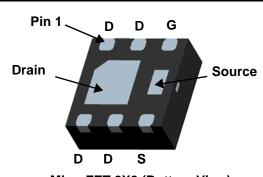
General Description

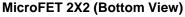
This device has been designed to provide maximum efficiency and thermal performance for synchronous buck converters. The low rDS(on) and gate charge provide excellent switching performance.

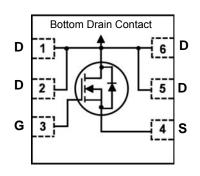
Application

■ DC – DC Buck Converters









MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Paran		Ratings	Units	
V_{DS}	Drain to Source Voltage		100	V	
V_{GS}	Gate to Source Voltage			±20	V
I _D	Drain Curre -Continuous	T _A = 25 °C	(Note 1a)	3.3	^
	-Pulsed		(Note 3)	20	A
D	Power Dissipation	T _A = 25 °C	(Note 1a)	2.4	W
P_{D}	Power Dissipation $T_A = 25 ^{\circ}\text{C}$ (Note 1b)		(Note 1b)	0.9	VV
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	52	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	145	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
151	FDMA86151L	MicroFET 2X2	7 "	8 mm	3000 units

Electrical Characteristics T_J = 25 °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		69		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80 V, V _{GS} = 0 V			1	μА
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1.0	2.0	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = 250 μ A, referenced to 25 °C		-6		mV/°C
		V _{GS} = 10 V, I _D = 3.3 A		60	88	
r	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 2.7 \text{ A}$		83	132	mΩ
r _{DS(on)} Static Drain to Source On Resistance	V_{GS} = 10 V, I_{D} = 3.3 A, T_{J} = 125 °C		102	150	11122	
g _{FS}	Forward Transconductance	V _{DD} = 5 V, I _D = 3.3 A		8.6		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V - 50 V V - 0 V		322	450	pF
Coss	Output Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1 \text{ MHz}$		55	80	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 1/11/12		3	5	pF
R_q	Gate Resistance		0.1	1.9	3.8	Ω

Switching Characteristics

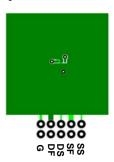
$t_{d(on)}$	Turn-On Delay Time	., -0,,,	5.6	12	ns
t _r	Rise Time	$V_{DD} = 50V, I_D = 3.3 A,$ $V_{GS} = 10 V, R_{GEN} = 6 \Omega$	1.4	10	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10 V, R _{GEN} = 6 Ω	11	20	ns
t _f	Fall Time		1.6	10	ns
$Q_{g(TOT)}$	Total Gate Charge	V _{GS} = 0 V to 10 V	5.2	7.3	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V}$ $V_{DD} = 50 \text{ V}$,	2.6	3.7	nC
Q _{gs}	Gate to Source Charge	I _D = 3.3 A	1.1		nC
Q _{qd}	Gate to Drain "Miller" Charge		1.0		nC

Drain-Source Diode Characteristics

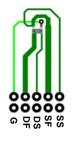
V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = 3.3 \text{ A}$ (Note 2)		0.8	1.2	V
t _{rr}	Reverse Recovery Time	L = 3 3 A di/dt = 100 A/		33	53	ns
Q _{rr}	Reverse Recovery Charge	I _F = 3.3 A, di/dt = 100 A/μs		25	40	nC

NOTES

^{1.} $R_{\theta JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.



a. 52 °C/W when mounted on a 1 in² pad of 2 oz copper.



 b. 145 °C/W when mounted on a minimum pad of 2 oz copper.

- 2. Pulse Test: Pulse Width < 300 $\mu\text{s},$ Duty cycle < 2.0%.
- 3. Pulsed Id limited by junction temperature, td<=10 μ S, please refer to SOA curve for more details.

Typical Characteristics T_J = 25°C unless otherwise noted

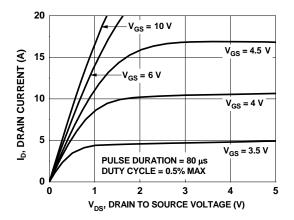


Figure 1. On-Region Characteristics

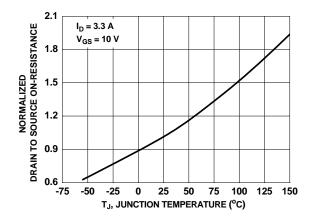


Figure 3. Normalized On-Resistance vs Junction Temperature

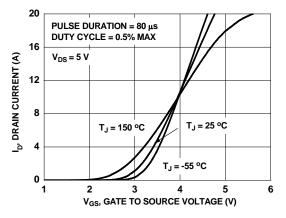


Figure 5. Transfer Characteristics

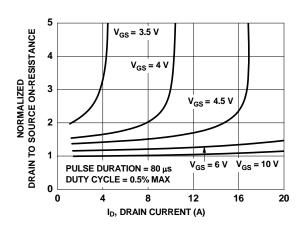


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

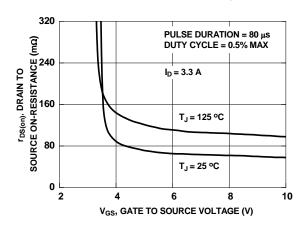


Figure 4. On-Resistance vs Gate to Source Voltage

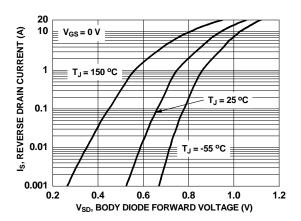


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted

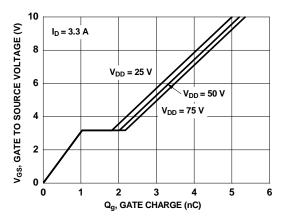


Figure 7. Gate Charge Characteristics

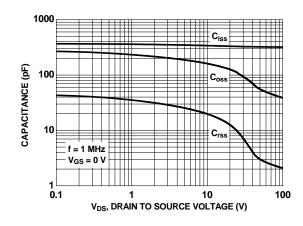


Figure 8. Capacitance vs Drain to Source Voltage

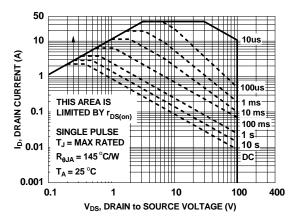


Figure 9. Forward Bias Safe Operating Area

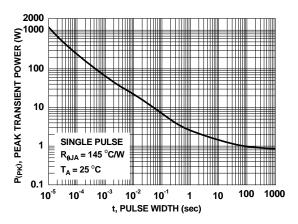


Figure 10. Single Pulse Maximum Power Dissipation

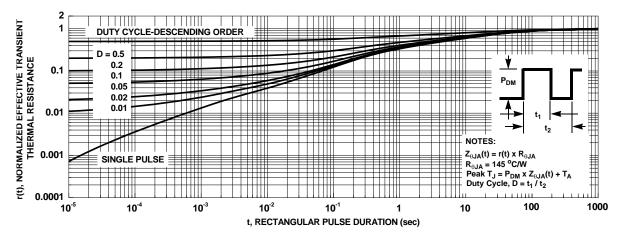
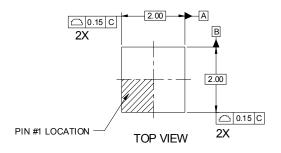
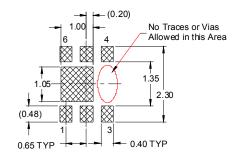


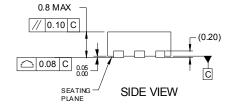
Figure 11. Single Pulse Junction-to-Ambient Transient Thermal Response Curve

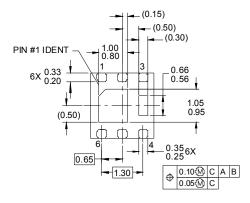
Dimensional Outline and Pad Layout

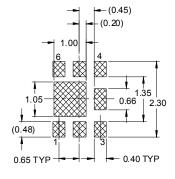




RECOMMENDED LAND PATTERN OPT 1







BOTTOM VIEW

RECOMMENDED LAND PATTERN OPT 2

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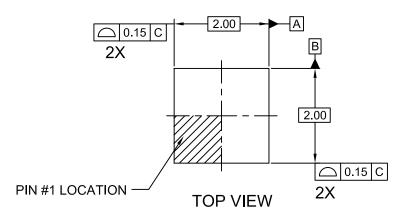
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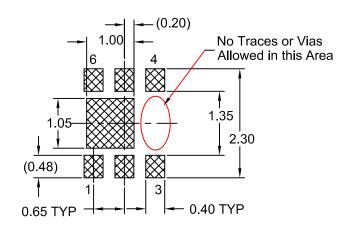
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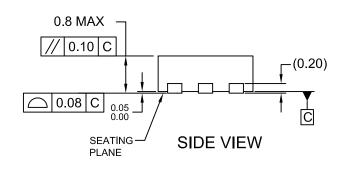
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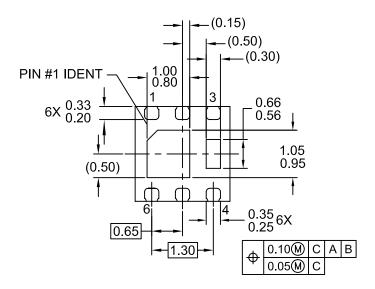
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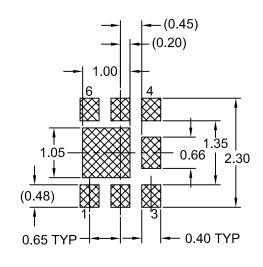




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RECOMMENDED LAND PATTERN OPT 2

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